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Structural and optical study of undoped and Ag-doped Sb₂S₃ polycrystals and thin films

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INTRODUCTION

Sb₂S₃ is a phase-change material characterised by extraordinary variation of optical parameters (band gap, refractive index) under reversible phase transitions between the crystalline and amorphous states. Its important advantage is very low optical absorption ($k < 10^{-5}$) in the near-infrared and visible spectral range both in the amorphous and crystalline states. This enables its application as a medium for building up neural networks. Thermal transport in Sb₂S₃ is dominated by the contribution of phonons rather than electronic thermal conductivity. This makes it promising for thermoelectric devices. Sb₂S₃ has a noticeable potential for applications in solar energy conversion. Doping Sb₂S₃ with silver, in particular, increases its refractive index, thereby making it attractive for applications in photonics as well as reduces its intrinsic high electric resistivity what is essential for its use as buffer layer in photovoltaics. Here we present an X-ray diffraction (XRD) and Raman spectroscopic study of polycrystalline Sb₂S₃ and Sb₂S₃:Ag ingots as well as thermally evaporated films of similar compositions.

EXPERIMENTAL

© Sb₂S₃ was synthesised from high-purity elemental Sb (99.999%) and S (99.9995%) by two-temperature synthesis with the "hot" (Sb-containing) zone temperature of 650 °C and subsequent cooling down to room temperature at a rate 50 K/h. (Sb₂S₃)_{1-x}Ag_x alloys were synthesised from Sb₂S₃ and colloidal Ag in evacuated quartz ampoules at 650 ^OC.

© 2.1–2.5 μm thick (Sb₂S₃)_{1–x}Ag_x films were prepared by flash evaporation at 1200 ^OC on cold silicon and silicate glass substrates without any post-preparation annealing of the films. \odot X-ray diffraction (XRD) studies were performed using an AXRD Benchtop diffractometer with Cu K_{α} radiation and a Ni filter.

◎ Micro-Raman spectra were measured at room temperature using a Horiba XPIoRa Plus spectrometer (532 nm laser, CCD camera, instrumental resolution better than 2.5 cm⁻¹).

RESULTS AND DISCUSSION

Polycrystals

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CONCLUSIONS

• Sb₂S₃:Ag polycrystals and thin films (Ag content up to 10 %) were obtained by high-temperature synthesis and thermal evaporation, respectively. XRD data confirmed the orthorhombic (stibnite) structure of the synthesised polycrystalline Sb₂S₃:Ag ingots, the Ag-containing samples show the presence of the AgSbS₂ phase as well. Raman measurements performed at a low laser power density P_{exc}=4 kW/cm² assume the possible presence of the AgSbS₂ phase, but cannot provide unambiguous evidence for its existence.

B Raman measurements at increased P_{exc}=40 kW/cm² revealed photostructural and photochemical transformations, namely the formation of elemental Sb and Sb₂O₃ phases due to the heating of the sample surface by the tightly focused laser light and oxidation by the ambient air.

This thermal effect is accompanied by a nonthermal effect of photoinduced material transport from the laser spot(well known for amorphous chalcogenides. Formation of the pit on the sample surface at Raman measurements performed in liquid isopropanol confirms the nonthermal nature of the photoinduced material transport.

6 In the Raman spectra of Sb₂S₃:Ag polycrystals immersed in liquid isopropanol measured at elevated P_{exc} elemental Sb features appear due to the chemical reaction on the surface induced by laser heating while the Sb2O3 -related features do not appear at all due to blocking the access of the ambient air by isopropanol.

6 Raman spectra of Sb₂S₃:Ag thin films measured at a low $P_{exc}=4$ kW/cm² clearly reveal their amorphous structure.

In the Raman spectra of Sb₂S₃:Ag thin films in isopropanol measured at elevated P_{exc} the Sb₂O₃ -related features appear since oxygen comes from voids in the film where it was stored since the film condensation after the evaporation.